

L Number	Hits	Search Text	DB	Time stamp
1	7	ferroelectric adj memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:41
2	18563	test adj circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:40
3	4582	ferroelectric adj memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:41
4	41	(test adj circuit) and (ferroelectric adj memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:42
5	108592	transistor near9 capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:42
6	17	((test adj circuit) and (ferroelectric adj memory)) and (transistor near9 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:43
7	36151	sense adj amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:44
8	2413	(sense adj amplifier) and bitline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:44
9	80	(test adj circuit) and ((sense adj amplifier) and bitline)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:44
10	441	capacitor adj test	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:45
11	0	((test adj circuit) and ((sense adj amplifier) and bitline)) and (capacitor adj test)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:45
12	3994	plate adj line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:46
13	18	((test adj circuit) and (ferroelectric adj memory)) and (plate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:46
15	359	differential adj read	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/08 13:47

16	0	differential adj read4 and (differential adj read)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/01/08 13:47
----	---	---	---	---------------------